

# Dielectronic Recombination of $W^{18+}$ : Theory vs Storage Ring Measurements

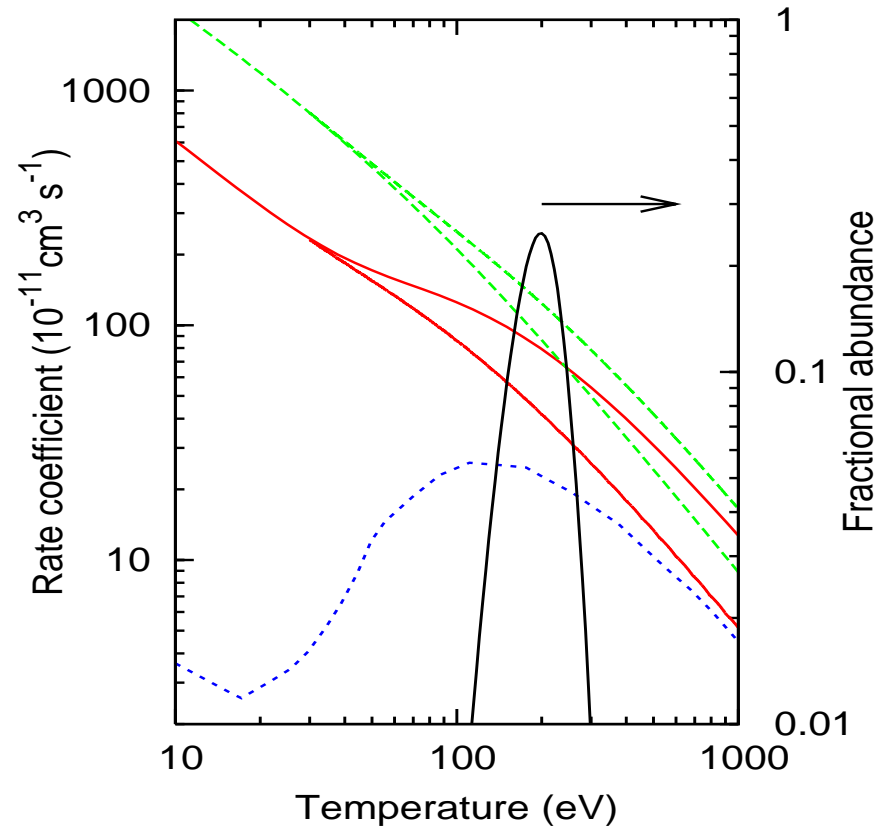
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## Motivation

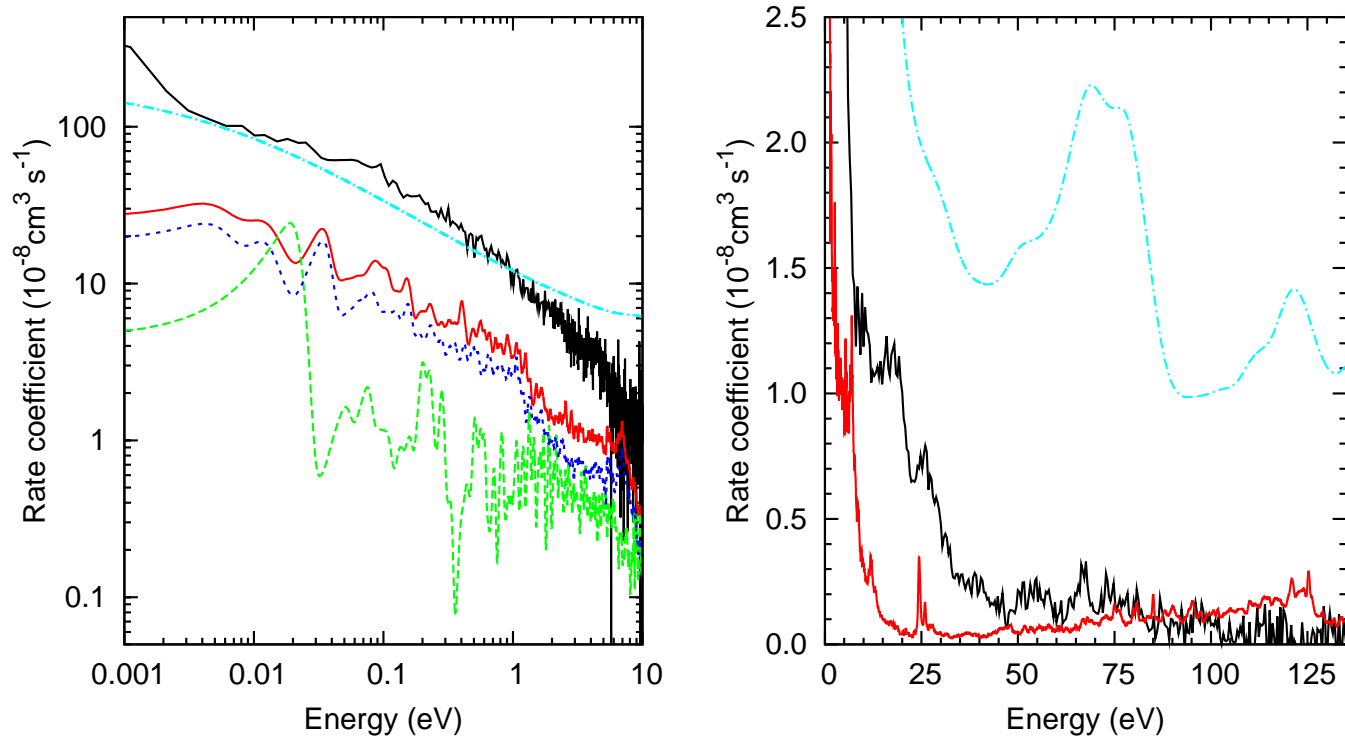
- Dielectronic recombination (DR) establishes the ionization balance in non-LTE plasmas and contributes to line emission e.g. DR satellites.
- For ITER and ITER-like devices we need to consider W and its brethren. The highest charge-state likely to be seen in ITER is nominally 60+.
- Tungsten  $\sim 20+$  is seen at the null point of the separatrix at JET.
- Previously, (ADAS 2012) reported-on DR of  $W^{20+}(4d^{10}4f^8 \ ^7F_6)$ : experiment (Schippers et al. PRA83, 012711, 2011) and theory (Badnell et al. PRA85, 052716, 2012).

## Recall (1): $W^{20+}$



**Fig 1.**  $W^{20+}$  total Maxwellian DR rate coefficients: experiment Schippers et al. (2011) to 140 eV and with theory top-up for resonances above 140 eV (long-dashed green curves); theory Badnell et al. (2012) IC all resonances and to 140 eV only (solid red curves), and ADAS (Foster, Ph.D. Thesis 2008) (short-dashed blue curve). A possible fractional abundance of  $W^{20+}$  in a magnetic fusion plasma is shown also (solid black curve).

## Recall (2): $W^{20+}$



**Fig 2.**  $W^{20+}$  merged-beams DR rate coefficients: experiment Schippers et al. (2011) (solid black curve); theory Badnell et al. (2012) partitioned total (dot-dashed cyan curve), IC total (solid red curve), LS total (long-dashed green curve), and IC  $4d \rightarrow 4f$  only (short-dashed blue curve).

## DR of $W^{18+}(4d^{10}4f^{10} 5I_8)$

We use AUTOSTRUCTURE (Badnell 2011) to carry-out configuration average, LS- and intermediate coupling calculations — including partitioning.

We consider  $\Delta n = 0$  and  $\Delta n = 1$  promotions of  $4d$  and  $4f$  electrons.

The complexity of the open f-shell restricts us to one-electron promotions plus dielectronic capture into autoionizing states of  $W^{17+}$ .

There are many more autoionizing states present which result from multiple-electron promotions (plus capture) but they are 'forbidden' to the ground state under a single 2-body operator.

The same open f-shell complexity mixes/redistributes the dielectronic capture (inverse autoionization  $A$ ) over many more autoionizing states, effectively making them accessible from the ground state.

Such 'forbidden' capture states can typically radiatively stabilize at a rate  $R$  comparable with that for the 'allowed' capture.

## A Simple Model

What does this mean for DR?

Recall,

$$\text{DR} \propto \frac{AR}{A + R} \quad (1)$$

and so the weaker process controls the rate:

If  $A \ll R$

$$\text{DR} \propto \frac{A}{A/R + 1} \approx A. \quad (2)$$

If  $R \ll A$

$$\text{DR} \propto \frac{R}{1 + R/A} \approx R. \quad (3)$$

So, if the autoionization rate  $A$ , corresponding to the allowed dielectronic capture, satisfies

$$A \ll R, \quad (4)$$

initially, then the total DR is merely redistributed by any (unitary) mixing transformation, and

$$\text{DR} \propto A \quad (5)$$

still, both with-and-without mixing.

However, if initially

$$A \gg R, \quad (6)$$

so

$$\text{DR} \propto R, \quad (7)$$

then following complete redistributive mixing of  $A$ , so that  $A \ll R$  again, we have the total

$$\text{DR} \propto A \quad (8)$$

and enhanced by a factor

$$A/R. \quad (9)$$

compared to the unmixed result.

## Redistribution, Partitioning & Damping

We use a Breit-Wigner distribution to partition our autoionization rates, as suggested by statistical theory (Flambaum et al. 1994):

$$A \leftarrow L(E)A \quad (10)$$

and

$$L(E) = \frac{\Gamma/(2\pi)}{E^2 + \Gamma^2/4}, \quad (11)$$

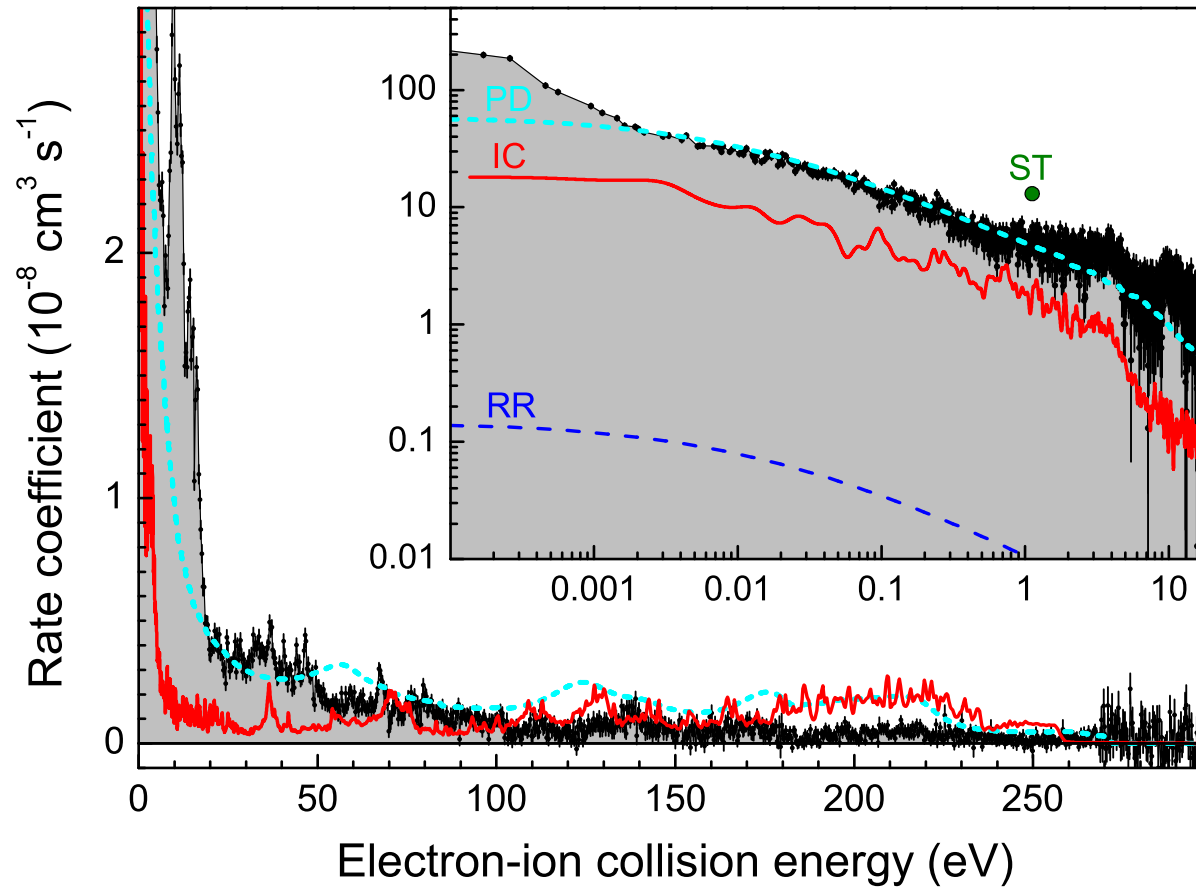
where  $E$  is the 'de-tuning' energy and  $\Gamma$  is the spreading width ( $\sim 10$  eV for the open f-shell). We use a uniform logarithmic set of 'bin' energies for  $E$ .

The above model is valid close to threshold only. As we move higher in energy, more-and-more alternative autoionization into excited-states pathways open-up and suppress the DR again ( $A + R \not\approx R$ ).

Thus, the total autoionization width needs to be recomputed at each bin energy (for each dielectronic capture).

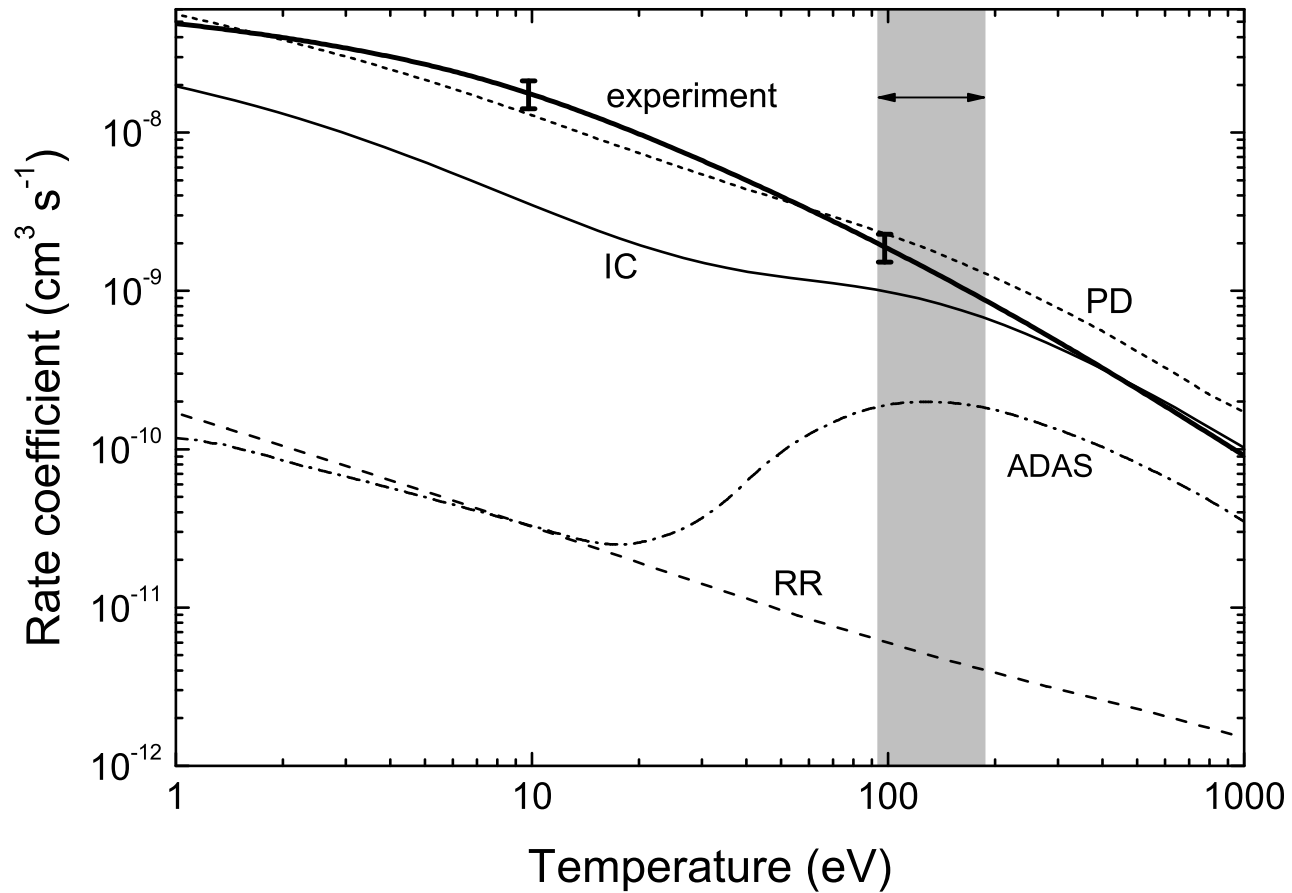


## $W^{18+}$ (New)



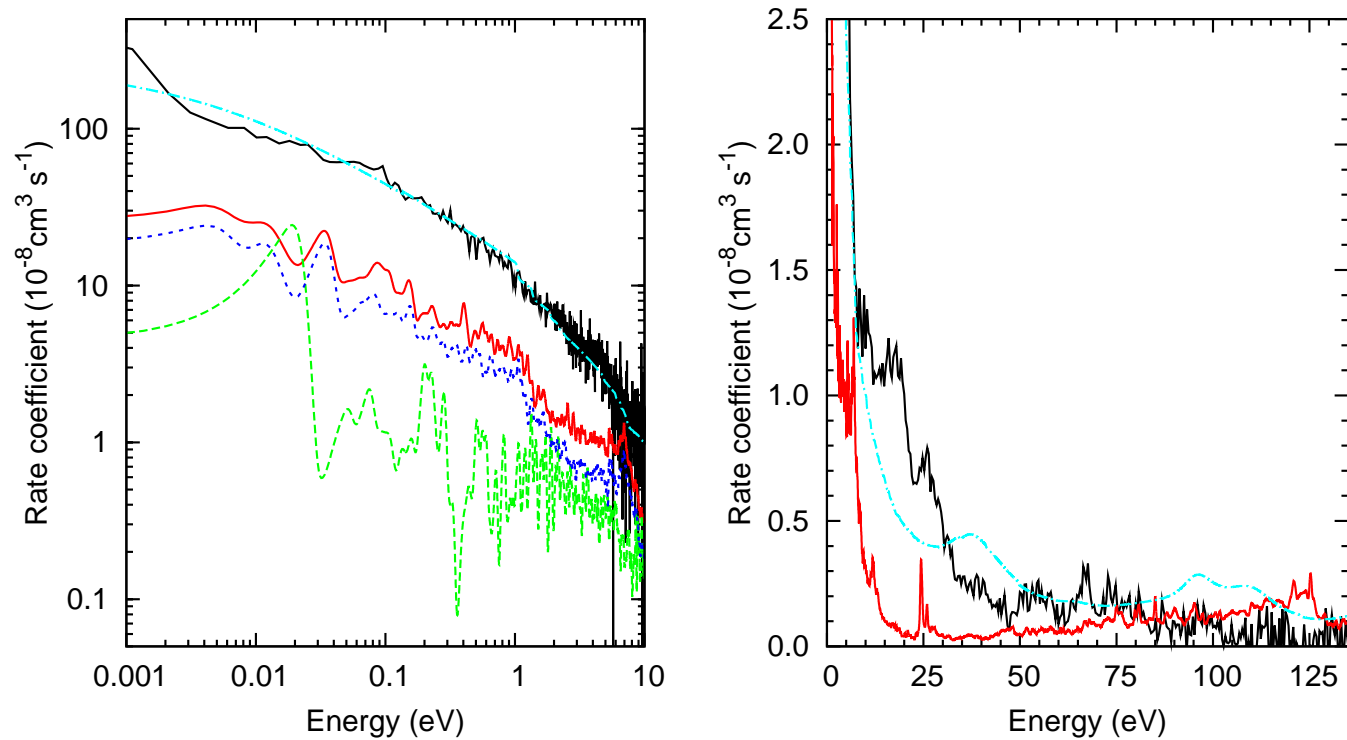
**Fig 3.** Merged-beams recombination rate coefficients for  $W^{18+}$  (Spruck et al. Phys.Rev.A At Press, 2014). Symbols with error bars: measured; solid curve (IC): present intermediate-coupling results; short-dashed curve (PD): present partitioned and damped results; circle (ST): from the statistical theory by Dzuba et al. (2012).

# $W^{18+}$ (New)



**Fig 4.** Plasma recombination rate coefficients for  $W^{18+}$  (Spruck et al. Phys.Rev.A At Press, 2014). Thick solid curve: experimentally derived rate coefficient; thin solid curve: IC theory; short-dashed curve (PD) partitioned and damped calculation; Dot-dashed curve: ADAS plasma recombination rate coefficient (Foster 2008).

## $W^{20+}$ (Revisited)



**Fig 5.**  $W^{20+}$  merged-beams DR rate coefficients: experiment Schippers et al. (2011) (solid black curve); theory Badnell et al. (2012, & unpublished) partitioned and damped total (dot-dashed cyan curve), IC total (solid red curve), LS total (long-dashed green curve), and IC 4d  $\rightarrow$  4f only (short-dashed blue curve).

## Follow-up

ADAS 2012 Workshop:

- CR modelling to assess density effects and revise ionization balance for W with open f-shell; × DR of adjacent ions expected to be similar. ✓
- Experiments on adjacent ions being analyzed (Schippers, private communication). ✓ (19+ almost finished.)
- Can the validity of the model calculation be extended to higher energy? ✓ ✓

## Follow-on

ADAS 2014 Workshop:

- We have a good handle on total DR. But CR modelling requires final-state resolved partials. We have the answer, viz. the hybrid *adf09* specification (discussed at ADAS 2012). The question is, where do we put the redistributed DR?
- EPSRC funded (EP/L021803/1) 'Atomic Process for Magnetic Fusion Plasmas: DR of the Tungsten Isonuclear Sequence' — starting shortly (Simon Preval) at Strathclyde, and Martin at JET.

# Podziękowania!